

SOT-89

Pin Definition:

1. Base
2. Collector
3. Emitter

PRODUCT SUMMARY

BV_{CBO}	-20V
BV_{CEO}	-20V
I_C	-3A
$V_{CE(SAT)}$	-0.2V @ $I_C / I_B = -2A / -100mA$

Features

- Low $V_{CE(SAT)}$ -0.2 @ $I_C / I_B = -2A / -100mA$ (Typ.)
- Complementary part with TSD2150

Structure

- Epitaxial Planar Type
- PNP Silicon Transistor

Ordering Information

Part No.	Package	Packing
TSB1424CY RM	SOT-89	1Kpcs / 7" Reel

Absolute Maximum Rating ($T_a = 25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Collector-Base Voltage	V_{CBO}	-20	V
Collector-Emitter Voltage	V_{CEO}	-20	V
Emitter-Base Voltage	V_{EBO}	-6	V
Collector Current	I_C	DC	-3
		Pulse	-5 (note1)
Collector Power Dissipation	P_D		0.6
			2 (note 2)
Operating Junction Temperature	T_J	+150	$^\circ C$
Operating Junction and Storage Temperature Range	T_{STG}	- 55 to +150	$^\circ C$

Note: 1. Single pulse, $P_w=10ms$, $Duty \leq 50\%$

2. When mounted on a 40 x 50 x 0.7mm ceramic board.

Electrical Specifications ($T_a = 25^\circ C$ unless otherwise noted)

Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Collector-Base Breakdown Voltage	$I_C = -50\mu A, I_E = 0$	BV_{CBO}	-20	--	--	V
Collector-Emitter Breakdown Voltage	$I_C = -10mA, I_B = 0$	BV_{CEO}	-20	--	--	V
Emitter-Base Breakdown Voltage	$I_E = -50\mu A, I_C = 0$	BV_{EBO}	-6	--	--	V
Collector Cutoff Current	$V_{CB} = -20V, I_E = 0$	I_{CBO}	--	--	-0.1	μA
Emitter Cutoff Current	$V_{EB} = -5V, I_C = 0$	I_{EBO}	--	--	-0.1	μA
Collector-Emitter Saturation Voltage	$I_C / I_B = -2A / -100mA$	$V_{CE(SAT)}$	--	-0.2	-0.5	V
DC Current Transfer Ratio	$V_{CE} = -2V, I_C = 100mA$	h_{FE}	120	--	390	
Transition Frequency	$V_{CE} = -2V, I_E = 0.5A,$ $f = 100MHz$	f_T	--	200	--	MHz
Output Capacitance	$V_{CB} = -10V, I_E = 0, f = 1MHz$	C_{ob}	--	28	--	pF

h_{FE} values are classified as follows:

Rank	Q	R
h_{FE}	120~270	180~390

Electrical Characteristics Curve (Ta = 25°C, unless otherwise noted)

Figure 1. DC Current Gain

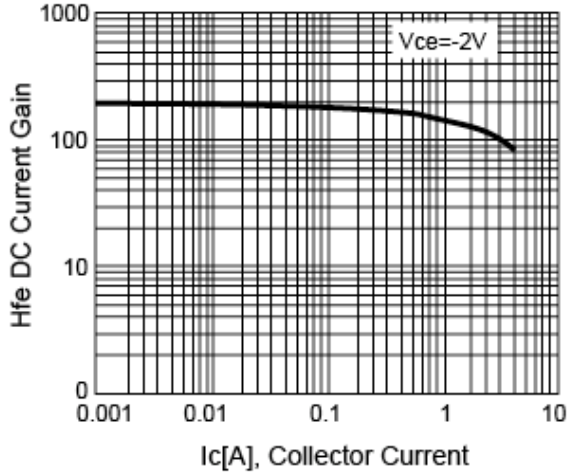


Figure 2. V_{CE(SAT)} v.s. Ic

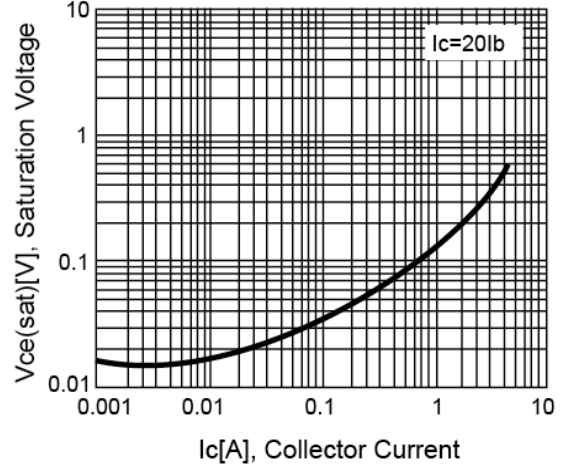


Figure 3. V_{BE(SAT)} v.s. Ic

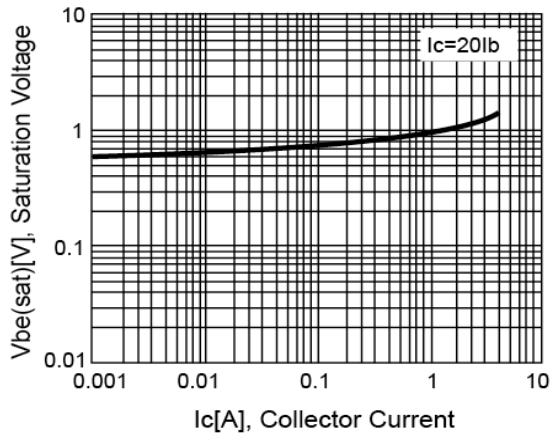


Figure 4. Transition Frequency v.s. I_E

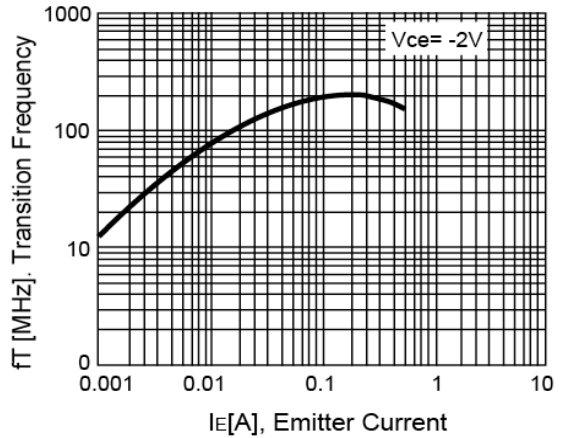


Figure 5. Collector Output Capacitance vs. Vcb

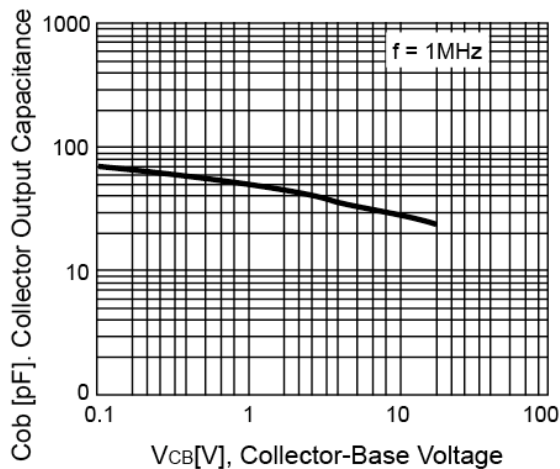
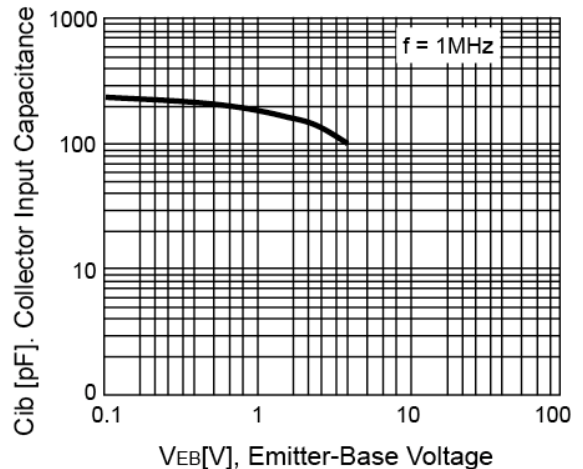
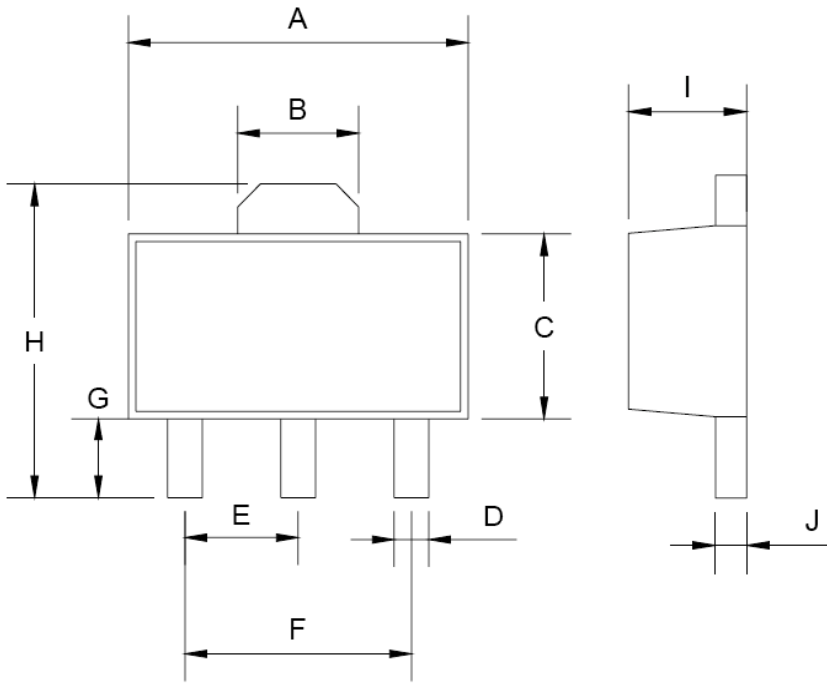


Figure 6. Collector Input Capacitance vs. Veb



SOT-89 Mechanical Drawing



SOT-89 DIMENSION				
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.40	4.60	0.173	0.181
B	1.50	1.7	0.059	0.070
C	2.30	2.60	0.090	0.102
D	0.40	0.52	0.016	0.020
E	1.50	1.50	0.059	0.059
F	3.00	3.00	0.118	0.118
G	0.89	1.20	0.035	0.047
H	4.05	4.25	0.159	0.167
I	1.4	1.6	0.055	0.068
J	0.35	0.44	0.014	0.017

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